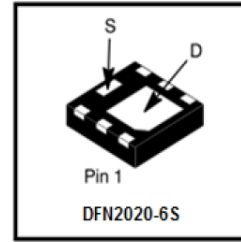


LN3406DT2AG

N-Channel 30V (D-S) MOSFET

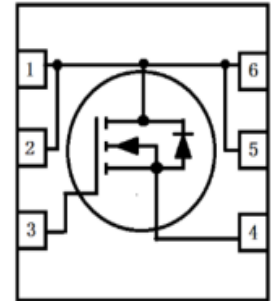
1. FEATURES

- Low RDS(on) trench technology
- Fast Switching Speed
- Low thermal impedance
- We declare that the material of product are Halogen Free and compliance with RoHS requirements.



2. APPLICATIONS

- White LED boost converters
- Automotive Systems
- DC-DC Converters



3. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LN3406DT2AG	N6S	4000/Tape&Reel

4. MAXIMUM RATINGS(Ta = 25°C unless otherwise stated)

Parameter		Symbol	Limits	Unit
Drain-to-Source Voltage		VDSS	30	V
Gate-to-Source Voltage		VGS	±8	V
Continuous Drain Current(Note 1)	TA =25°C	ID	10	A
	TA =70°C		8.1	
Pulsed Drain Current (Note 2)		IDM	40	A
Maximum Power Dissipation(Note 1)	TA =25°C	PD	2.1	W
	TA =70°C		1.3	
Operating Junction and Storage Temperature Range		TJ/Tstg	-55 ~+150	°C

5. THERMAL CHARACTERISTICS

Parameter		Symbol	Limits	Unit
Maximum Junction-to-Ambient(Note 1)	t ≤10s	RθJA	62.5	°C/W
	Steady State		110	

1.Surface mounted on "1.5 x 1.5" FR4 board using 1 sq in pad, 2 oz Cu.

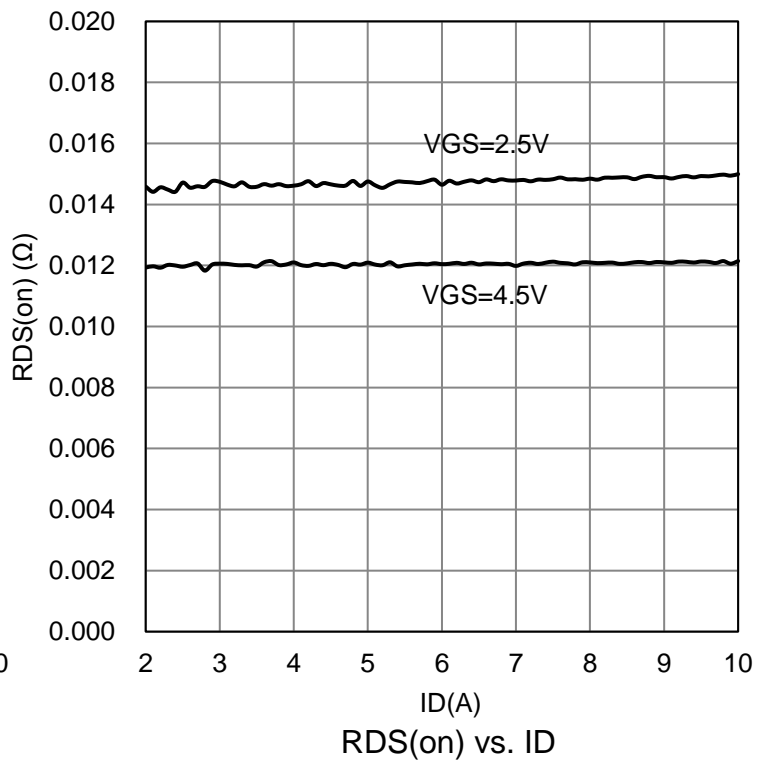
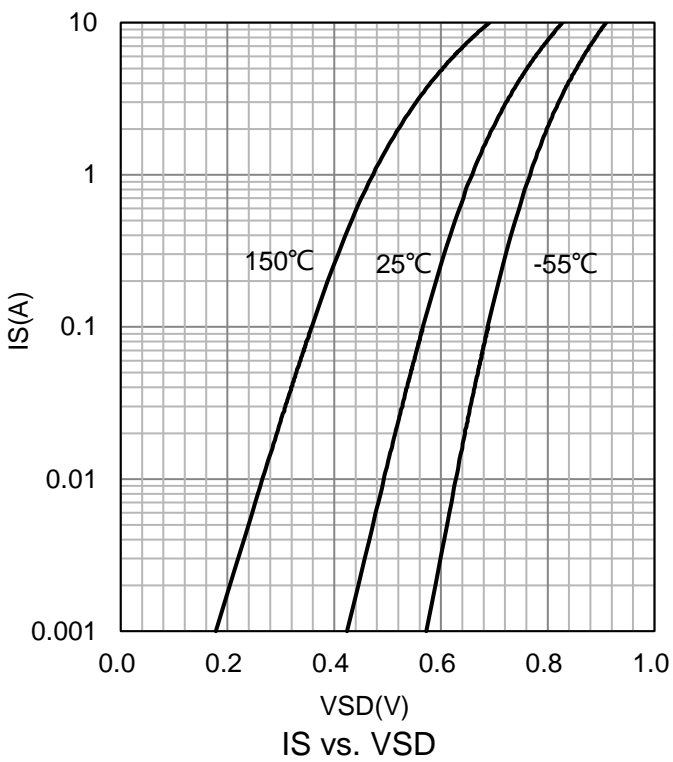
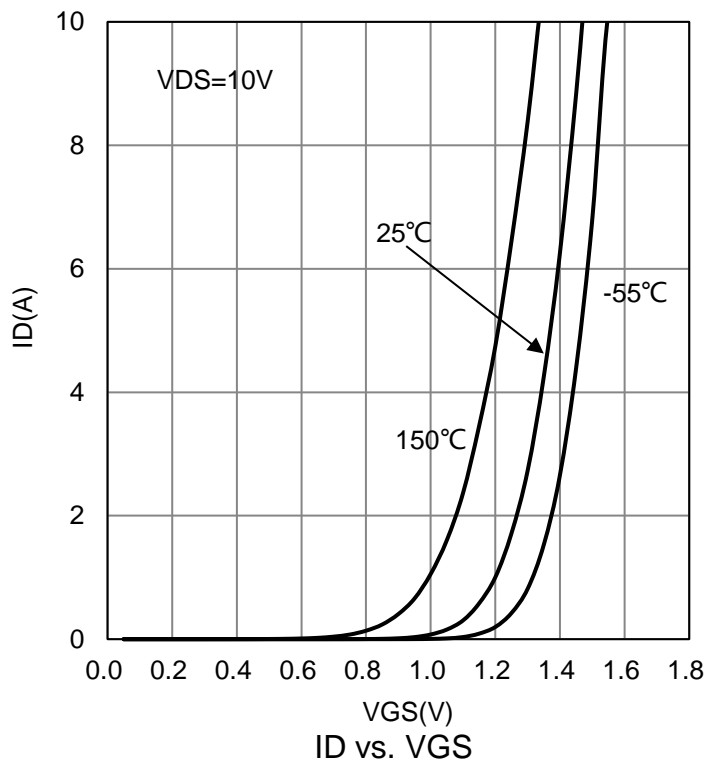
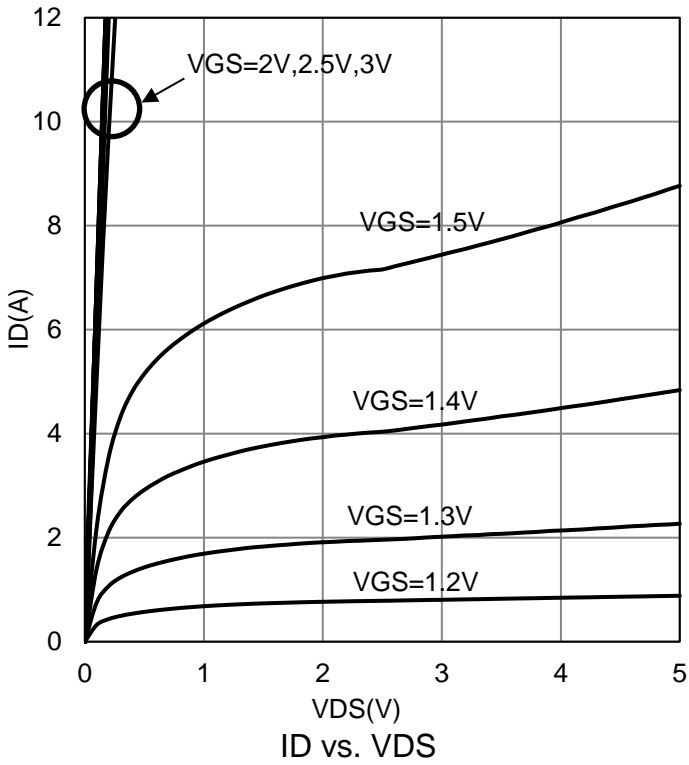
2.Pulse width limited by maximum junction temperature

6. ELECTRICAL CHARACTERISTICS

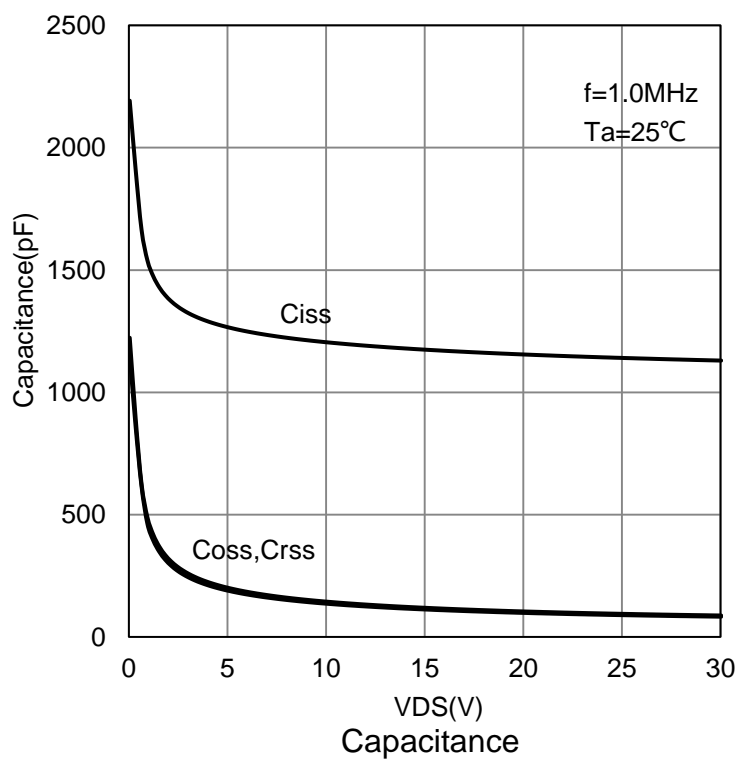
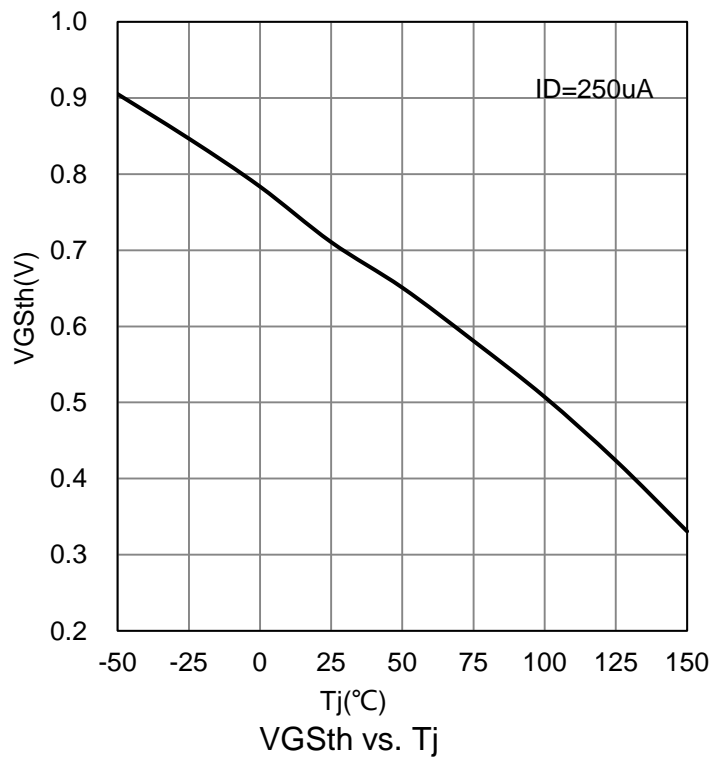
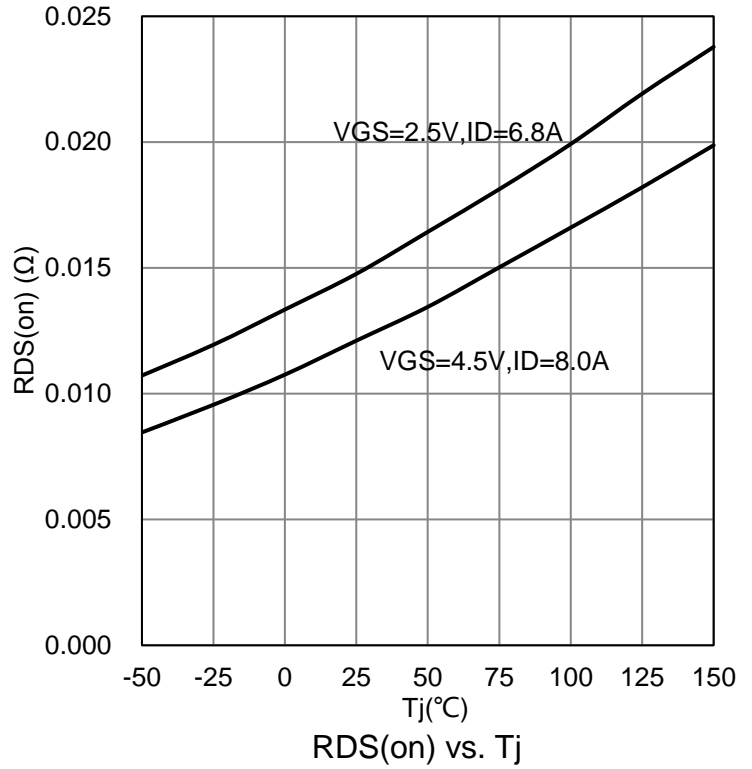
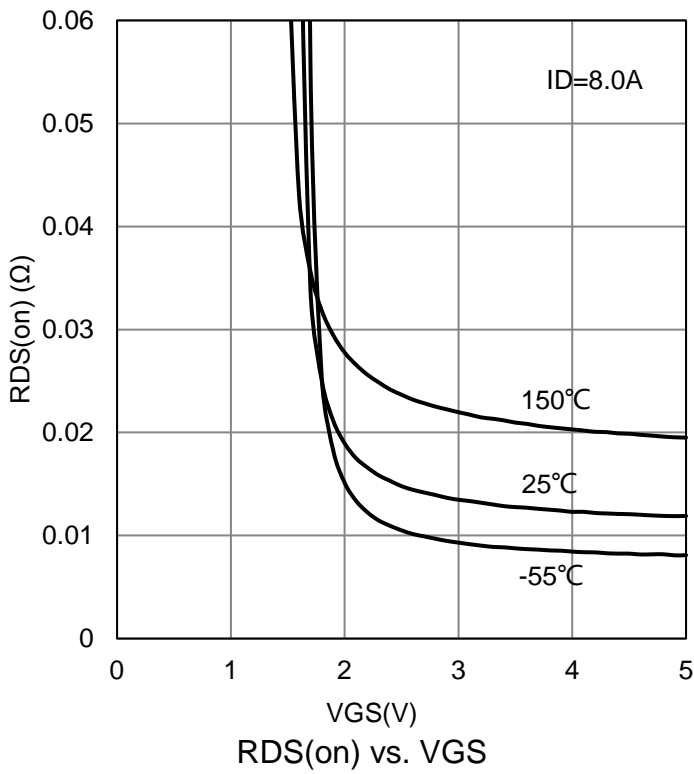
Characteristic	Symbol	Min.	Typ.	Max.	Unit	
Static						
Drain-Source Breakdown Voltage (VGS = 0V, ID = 250μA)	V(BR)DSS	30	-	-	V	
Gate-Source Threshold Voltage (VDS = VGS, ID = 250μA)	VGS(th)	0.4	-	1.3	V	
Gate Leakage Current (VDS = 0V, VGS = ±8V)	IGSS	-	-	±100	nA	
Zero Gate Voltage Drain Current (VDS = 24 V, VGS = 0 V) (VDS = 24 V, VGS = 0 V, TJ = 55°C)	IDSS	-	-	1 25	μA	
Drain-Source On-Resistance (VGS = 4.5V, ID = 8A) (VGS = 2.5V, ID = 6.8A)	RDS(ON)	-	-	13.5 20	mΩ	
Diode Forward Voltage (IS = 1.7 A, VGS = 0 V)	VSD	-	0.68	-	V	
DYNAMIC						
Total Gate Charge	(VDS = 15V, VGS = 4.5V, ID = 8A)	Qg	-	24	-	nC
Gate-Source Charge		Qgs	-	5	-	
Gate-Drain Charge		Qgd	-	6.8	-	
Turn-On Delay Time	(VDS = 15V, RL = 1.9Ω, ID = 8A, VGEN = 4.5V, RGEN = 6Ω)	td(on)	-	19	-	ns
Turn-On Rise Time		tr	-	25	-	
Turn-Off Delay Time		td(off)	-	105	-	
Turn-Off Fall Time		tf	-	33	-	
Input Capacitance	(VDS = 15V, VGS = 0V, f = 1MHz)	Ciss	-	2141	-	pF
Output Capacitance		Coss	-	229	-	
Reverse Transfer Capacitance		Crss	-	205	-	

3. Pulse test; pulse width ≤ 300μs, duty cycle ≤ 2%

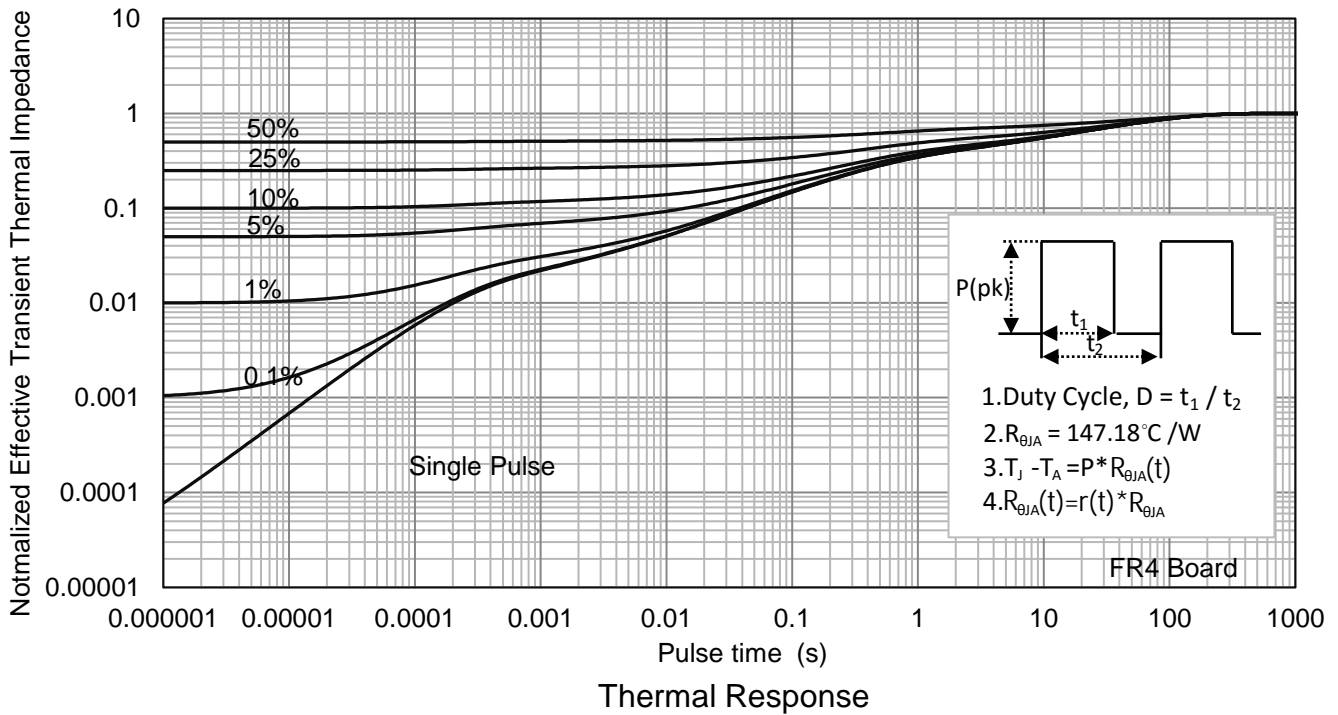
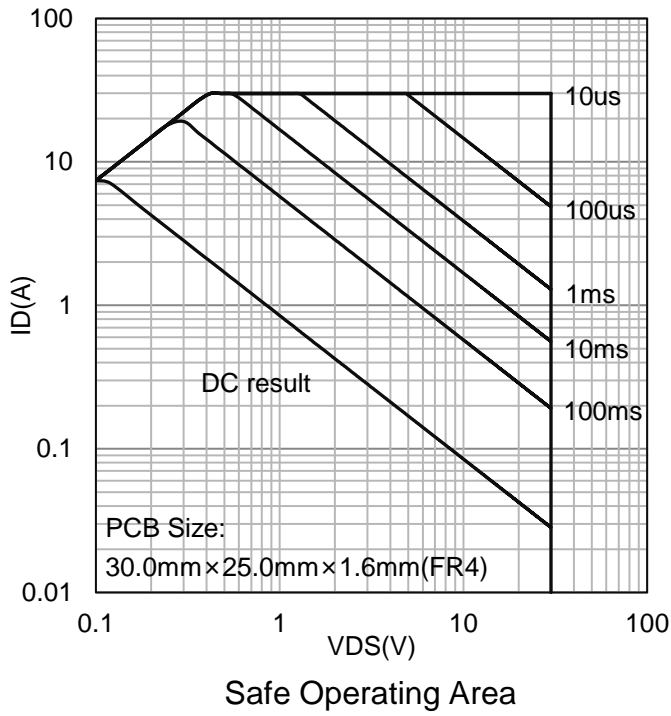
7.ELECTRICAL CHARACTERISTICS CURVES



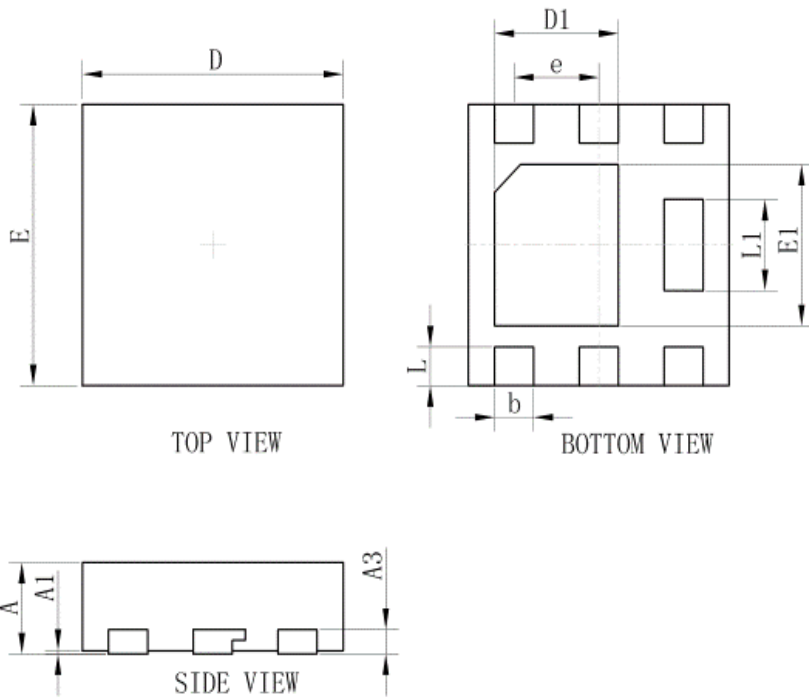
7.ELECTRICAL CHARACTERISTICS CURVES(Con.)



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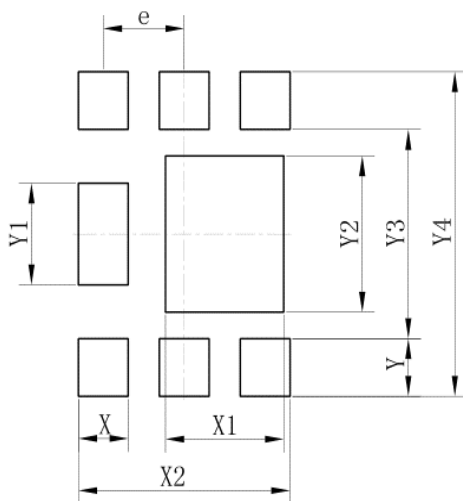


8. OUTLINE AND DIMENSIONS



DFN2020-6S			
DIM	MIN	NOR	MAX
A	0.60	0.65	0.70
A1	0.01	0.03	0.05
b	0.25	0.30	0.35
D	1.95	2.00	2.05
E	1.95	2.00	2.05
e	0.65TYP.		
L	0.23	0.28	0.33
L1	0.60	0.65	0.65
D1	0.90	0.95	1.00
E1	1.10	1.15	1.20
A3	0.152REF		
All Dimensions in mm			

9. SOLDERING FOOTPRINT



DFN2020-6S	
Dim	(mm)
X	0.40
X1	0.95
X2	1.70
e	0.65
Y	0.43
Y1	0.75
Y2	1.15
Y3	1.54
Y4	2.39

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